1 Characteristics

51

Table 1. Absolute ratings (limiting values at 25 °C unless otherwise specified, per diode)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	120	V	
I _{F(RMS)}	Forward rms current	30	А	
1	Average forward current , $T_c = 145 \text{ °C}$, $\delta = 0.5$	Per diode	20	•
I _{F(AV)}	Average forward current, $T_c = 145^{\circ}$ C, $0 = 0.5^{\circ}$ Per device		40	A
I _{FSM}	Surge non repetitive forward current t_p = 10 ms sinusoidal		200	Α
P _{ARM}	Repetitive peak avalanche power $t_p = 10 \ \mu s, T_j = 125 \ ^{\circ}C$		755	W
T _{stg}	Storage temperature range	-65 to +175	°C	
Tj	Maximum operating junction temperature (1)	175	°C	

1. $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

Symbol	Parameter	Max. value	Unit	
P	Junction to case	Per diode	1.6	°C/W
R _{th(j-c)}	Junction to case	Total	0.85	
R _{th(c)}	Coupling		0.1	

When the diodes 1 and 2 are used simultaneously: ΔT_j (diode 1) = P(diode 1) x R_{th(j-c)}(per diode) + P(diode 2) x R_{th(c)}

Table 3. Static electrical characteristics

Symbol	Parameter	Test co	Min.	Тур.	Max.	Unit	
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}	-		25	μA
IR ⁽¹⁾		T _j = 125 °C	VR - VRRM	-	4	12	mA
	Forward voltage drop	T _j = 25 °C	I _F = 7.5 A	-		0.73	V
		T _j = 125 °C		-	0.57	0.61	
V _F ⁽²⁾		T _j = 25 °C	I _F = 20 A	-		0.90	
vF		T _j = 125 °C		-	0.69	0.73	
		T _j = 25 °C		-		1.00	
		T _j = 125 °C		-	0.83	0.88	

1. Pulse test: $t_p = 5 ms$, $\delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses, use the following equation:

 $P = 0.58 \text{ x } I_{F(AV)} + 0.0075 \text{ x } I_{F}{}^{2}_{(RMS)}$

For more information, please refer to the following application notes related to the power losses :



- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

1.1 Characteristics (curves)

Figure 3. Normalized avalanche power derating versus

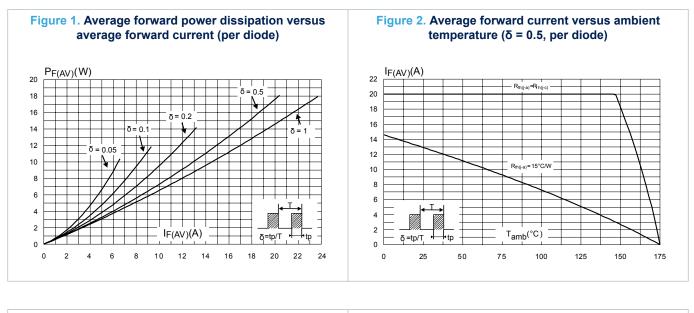
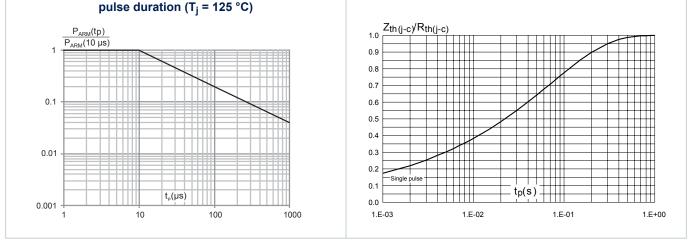
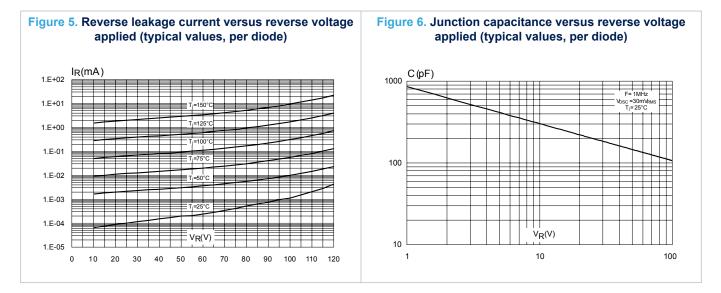


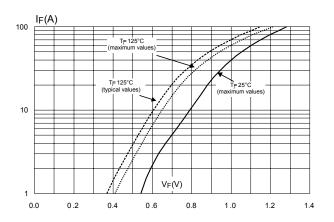
Figure 4. Relative variation of thermal impedance junction to case versus pulse duration











2 Package information

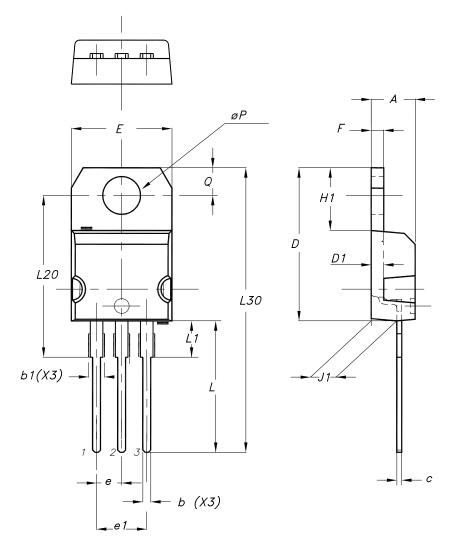
57

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

2.1 TO-220AB package information

- Epoxy meets UL 94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N·m
- Maximum torque value: 0.70 N·m

Figure 8. TO-220AB package outline



	Dimensions				
Ref.	Millimeters		Inches (for re	ference only)	
	Min.	Max.	Min.	Max.	
А	4.40	4.60	0.173	0.181	
b	0.61	0.88	0.240	0.035	
b1	1.14	1.55	0.045	0.061	
С	0.48	0.70	0.019	0.028	
D	15.25	15.75	0.600	0.620	
D1	1.27	′ typ.	0.050 typ.		
E	10.00	10.40	0.394	0.409	
е	2.40	2.70	0.094	0.106	
e1	4.95	5.15	0.195	0.203	
F	1.23	1.32	0.048	0.052	
H1	6.20	6.60	0.244	0.260	
J1	2.40	2.72	0.094	0.107	
L	13.00	14.00	0.512	0.551	
L1	3.50	3.93	0.138	0.155	
L20	16.4	16.40 typ.		6 typ.	
L30	28.9	0 typ.	1.138 typ.		
θΡ	3.75	3.85	0.148	0.152	
Q	2.65	2.95	0.104	0.116	

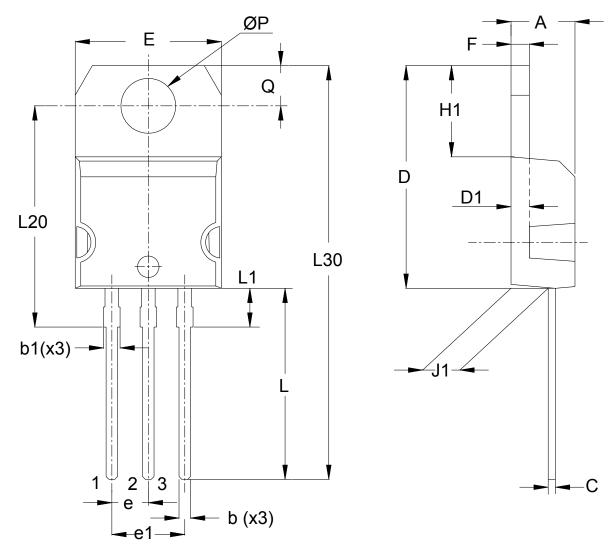
Table 4. TO-220AB package mechanical data



2.2 TO-220AB narrow leads package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N·m
- Maximum torque value: 0.70 N·m

Figure 9. TO-220AB narrow leads package outline



	Dimensions				
Ref.	Millimeters		Inches (for reference only)		
	Min.	Max.	Min.	Max.	
А	4.40	4.60	0.173	0.181	
b	0.61	0.88	0.240	0.035	
b1	0.95	1.20	0.037	0.047	
С	0.48	0.70	0.019	0.028	
D	15.25	15.75	0.600	0.620	
D1	1.2	1.27 typ.) typ.	
E	10.00	10.40	0.394	0.409	
e	2.40	2.70	0.094	0.106	
e1	4.95	5.15	0.195	0.203	
F	1.23	1.32	0.048	0.052	
H1	6.20	6.60	0.244	0.260	
J1	2.40	2.72	0.094	0.107	
L	13.00	14.00	0.512	0.551	
L1	2.60	2.90	0.138	0.155	
L20	15.40 typ.		0.646 typ.		
L30	28.90 typ.		1.138 typ.		
θΡ	3.75	3.85	0.148	0.152	
Q	2.65	2.95	0.104	0.116	

Table 5. TO-220AB narrow leads package mechanical data



3 Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS40120CT	STPS40120CT	TO-220AB	1.95 g	50	Tube
STPS40120CTN	PS40120CTN	TO-220AB narrow leads	1.9 g	50	Tube

Table 6. Ordering information

Revision history

Table	7.	Document	revision	history
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Date	Version	Changes			
18-Feb-2005	1	First issue			
1-Dec-2006	2	Reformatted to current standards. Added I ² PAK.			
15-Sep-2011	3	Added TO-220AB narrow leads package.			
21-Jun-2018	4	Removed I ² PAK package, figure 4 and figure 5. Updated Figure 3. Normalized avalanche power derating versus pulse duration (T_j = 125 °C) and Table 1. Absolute ratings (limiting values at 25 °C unless otherwise specified, per diode). Minor text changes to improve readability.			



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